



LBI-30751E

(DF3166)

(DF3172, IMTS)

MAINTENANCE MANUAL

138-174 MHz, 40 WATT POWER AMPLIFIER

19D424583G2 MOBILE "M" SERIES AND INTERMITTENT DUTY STATION

19D424583G6 MOBILE "E" SERIES

19D424786G2 CONTINUOUS DUTY STATION

19D424786G5 CONTINUOUS DUTY DUPLEX

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DESCRIPTION

The MASTR® II modularized 40-Watt PA assembly contains a 10-watt driver module, a 40-watt PA module, power control circuitry and low pass filter. A total of three transistors, two in the 10-watt driver and one in the 40-watt PA, are used to provide rated RF output power. The output power is adjustable from 10 watts to rated output power and is held constant for normal variations in temperature and voltage.

CAUTION

Mobile and Station Power Amplifier Assemblies ARE NOT interchangeable due to different chassis grounding requirements.

However, the individual driver and power amplifier board may be interchanged between mobiles and stations.

Supply voltage for the PA is connected through power leads from the system board to feedthrough capacitors C297 and C298 on the bottom of the PA assembly. C297, C298, C299 and L201 prevent RF from getting on the power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed, providing reverse voltage protection for the radio.

The PA assembly is insulated from vehicle ground to permit operation in positive or negative ground vehicles.

NOTE

In positive ground vehicles, A - is "hot" with respect to vehicle ground. Shorting the transmitter PA printed wiring board ground pattern to the radio case may cause one of the in-line fuses to blow.

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3A11 or Test Kit 4EX8K12. The Test Set meters Ampl-1 drive (exciter output), power control voltage, driver and PA current.

CIRCUIT ANALYSIS

10-WATT DRIVER A201

The exciter output is coupled through an RF cable to PA input jack J201. The RF is coupled through a matching network to the base of Class C amplifier Q1. The coupling network matches the 50-ohm input to the base of Q1 and consists of A201-T1, C4, C5, and C39. R3, C3, R13 and L1 are stabilizing networks in the base circuit of Q1.

Part of the RF input is rectified by CR1 and is applied to voltage divider R1 and R2. The voltage is divided to activate the Power Control circuits and for metering the Ampl-1 drive at J205.

Collector voltage to Q1 and Q2 is controlled by the Power Control circuit, and is applied to Q1 through collector

stabilizing network L4 and R4 and collector feed network L3 and C6. The collector voltage is metered through R7 at J205-3 (Pos. C).

The output of Q1 is coupled to the base of the second class C amplifier Q2 through a matching network consisting of C10 through C14 and L5 through L7. Collector voltage to Q2 is applied through collector stabilizing network L11 and R6 and collector feed network L8 and C15.

The output of the 10-watt driver is taken from the collector of Q2 and applied to the base of power amplifier A204-Q1 on the 40-watt PA module through an impedance matching network, two 50 ohm micro strips, W30 and a second impedance matching network.

The collector impedance matching network for A201-Q2 (L9, L10, C20 and C21) matches the output of Q2 to 50 ohm micro strip A201-W2. C22 is a DC blocking capacitor. W30 interconnects the output of the 10-watt driver to the input of the 40-watt PA module.

40-WATT PA MODULE A204

The base impedance matching network for A204-Q1 (L1-L3, C1-C4, and R1) matches the 50 ohm input impedance to the base of power amplifier A204-Q1. Collector voltage is coupled through collector stabilizing network Z1 and collector feed network L4 and C10.

Collector current for Q1 is metered across tapped manganin resistor R15 at J205-5&5. The reading is taken on the 10-volt scale with the High Sensitivity button pressed and read as 10 amperes full scale.

Following Q1 is an impedance matching network consisting of L5, L6, C7 and C9 that matches the output of Q1 to 50 ohm micro strip W2. The RF energy is then coupled through W31 and the low pass filter to the antenna.

WARNING

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

POWER CONTROL CIRCUIT

The power control circuit, located on the 10-watt driver module and PA Assembly, consists of power control IC A201-U1, thermistor RT201, power adjust potentiometer A201-R8, pass transistor Q215 and the directional coupler. The power control IC senses the presence of drive power from the exciter, the heat sink temperature, power output level, reflected power, and input voltage to provide automatic power leveling across the frequency band.

When the transmitter is keyed, rectified RF from A201-CR1 is applied to pin 10 of U1, turning it on. U1 supplies a reference voltage through pin 4 to power adjust potentiometer A201-R8. The voltage appearing at the arm of R8 is applied back to pin 2 of U1. This voltage determines the base voltage of Q215. The conduction of Q215 sets the collector voltage applied to the 10-watt driver transistors A201-Q1 and Q2, thereby controlling the RF drive to the PA. The RF output power varies in direct proportion to the RF drive applied to the PA and can be adjusted from approximately 10 to 40-watts.

Once the power is set to the desired level, U1 compares the setting of power adjust control R8 to the actual output power flowing through the directional coupler and adjusts the collector voltage on the 10-watt driver transistors accordingly. A204-CR1 rectifies the sensed forward power from the directional coupler and A204-R2 sets the forward power reference voltage applied to pin 1 of U1.

Reflected power is sensed by the directional coupler and rectified by A204-CR2. When the reflected power exceeds a preset level established by A204-R3, a DC voltage proportional to the reflected power is applied to pin 3 of U1. U1 lowers the base voltage of Q215, which in turn lowers the collector voltage of A201-Q1, Q2 thereby reducing transmitter output power.

Temperature protection is provided by U1 and thermistor RT201. RT201 is mounted on the heat sink assembly. Under normal operating conditions, the temperature sensing circuit is inactive. When the heat-sink temperature reaches approximately 100°C, the resistance of RT101 decreases, decreasing the base voltage of Q215. This in turn reduces the collector voltage applied to A201-Q1, Q2 reducing the transmitter output until at approximately 125°C the output power is almost zero. As the temperature of the heatsink decreases the output power increases until full power returns at approximately 100°C.



GE Mobile Communications

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Lynchburg, Virginia 24502

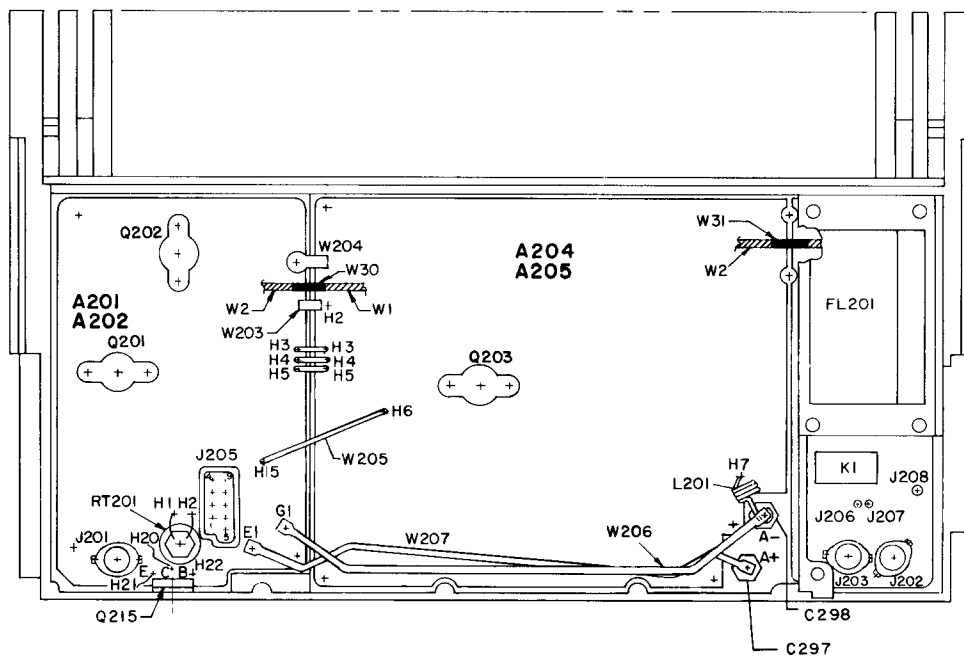
Overvoltage protection for the RF transistors is also provided by U1. Should the supply voltage exceed approximately 18 volts, U1 will switch off the collector voltage to A201-Q1, Q2 turning them off and thereby removing drive to the PA. The IC will hold A201-Q1, Q2 off until the supply voltage is reduced to a safe level.

CAUTION

U1 may be damaged if output terminals 12 or 14 are shorted to ground. Use extreme caution when servicing the power control circuit.

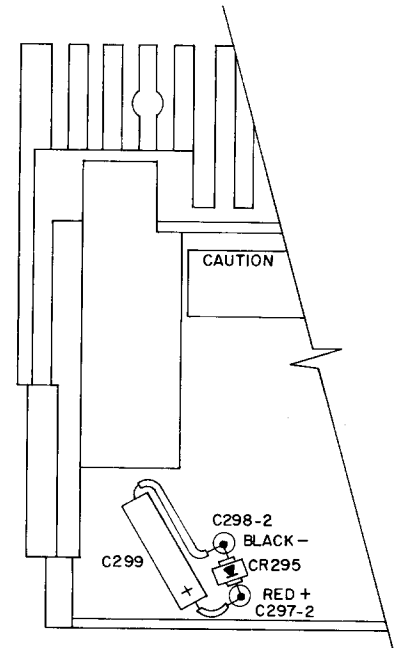
MOBILE AND INTERMITTENT DUTY STATION PA

TOP VIEW



(19D429850, Rev. 1)

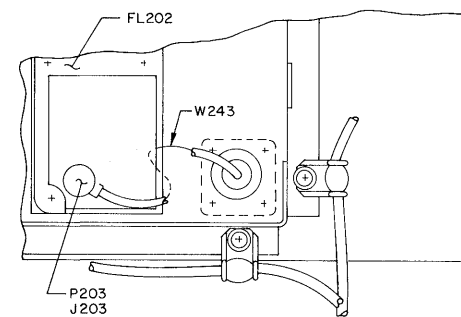
BOTTOM VIEW



OUTLINE DIAGRAM

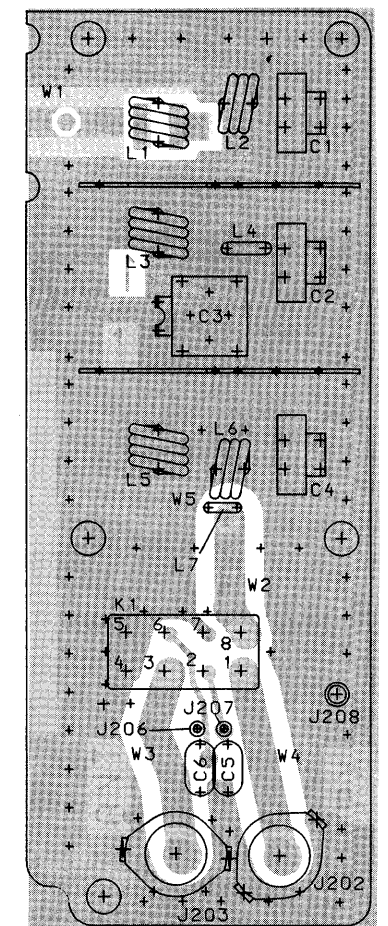
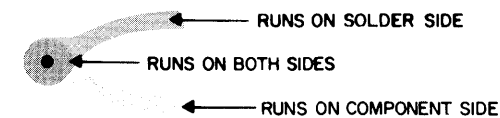
138—174 MHz 40 WATT POWER AMPLIFIER

STATION PA

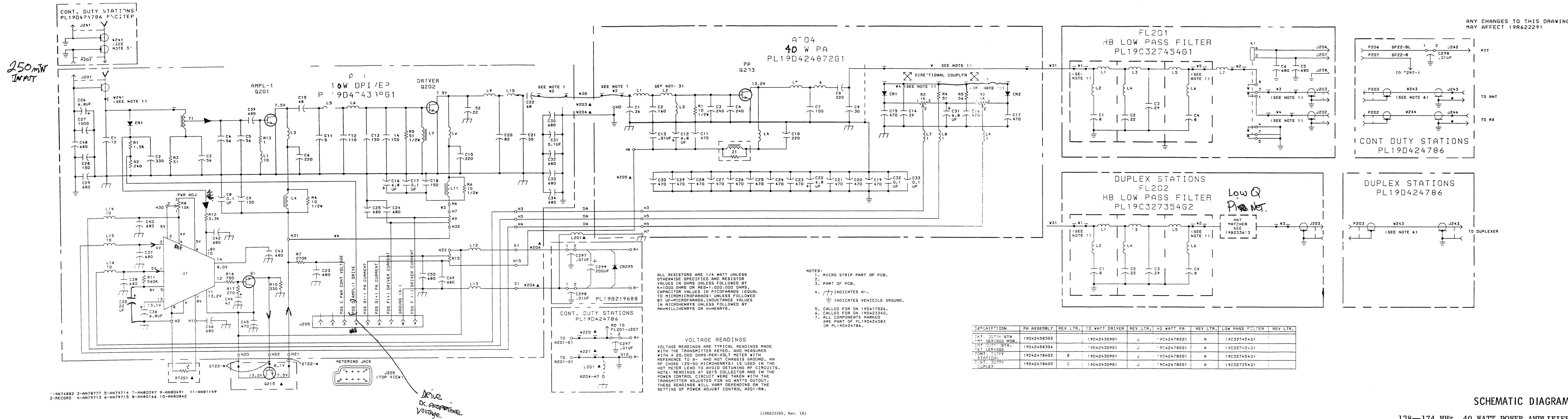


(19D429849, Rev. 2)

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(19C327842, Rev. 1)
(19B227654, Sh.1, Rev. 1)
(19B227654, Sh.2, Rev. 1)



PARTS LIST		
138-174 MHz POWER AMPLIFIER ASSEMBLIES		
19D424583G1	25 WATT "M" SERIES MARINE	
19D424583G2	40 WATT "M" SERIES MOBILE & INT. DUTY STATION	
19D424583G3	65 WATT "M" SERIES MOBILE & INT. DUTY STATION	
19D424583G4	110 WATT "M" SERIES MOBILE & INT. DUTY STATION	
19D424583G5	25 WATT "E" SERIES MARINE	
19D424583G6	40 WATT "E" SERIES MOBILE	
19D424583G7	65 WATT "E" SERIES MOBILE	
19D424583G8	110 WATT "E" SERIES MOBILE	
ISSUE 8		

SYMBOL	GE PART NO.	DESCRIPTION
A201	19D424309G1	10 Watt Driver. (Used with 19D424583G2, G4, G6 & G8).
A202	19D424309G3	25 Watt Driver/PA. (Used with 19D424583G1, G3, G5, & G7).
A203	19D424328G1	Coupler. (Used with 19D424583G1, G5).
A204	19D424872G1	40 Watt Power Amplifier. (Used with 19D424583G2, G6).
A205	19D424872G2	65 Watt Power Amplifier. (Used with 19D424583G3, G7).
A206	19D424266G1	110 Watt Power Amplifier. (Used with 19D424583G4, G8).
FL201	COMPONENT BOARD 19C327454G1	
	CAPACITORS	
	C1	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
	C2	19A700015P12 Teflon/Mica: 22 pF ±5%, 250 VDCW.
	C3	19A116795P29J Teflon: 29 pF ±5%, 250 VDCW.
C4	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
	C5 and C6	19A116655P18 Ceramic disc: 680 pF ±10%, 1000 VDCW; sim to RMC Type JF Discap.
	JACKS AND RECEPTACLES	
	J202 and J203	19A700049P2 Connector, receptacle: 500 VDCW maximum; sim to NTPF-1058.
	J206 and J207	19A134263P2 Contact, electrical: sim to Selectro 229-1071.
J208	4033513P4	Contact, electrical: sim to Bead Chain L93-3.
RELAYS		
K1	19A700061P1	Hermetic sealed: 180 to 341 ohms coil res, 8-16.3 VDC; sim to GE 3SAV1760A2, CPClare HPW-1201558, or Potter-Brumfield HCM6160.
INDUCTORS		
L1	19A129569P1	Coil.
L2	19A701418P1	Coil.
L3	19A129569P1	Coil.
L4	19A701420P5	Coil.
L5	19A129569P1	Coil.
L6	19A701418P1	Coil.
L7	19A136907P1	Coil.
CABLES		
W1 thru W5	(Part of printed board 19D424357P1).	

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
L201 and L202	19A129562P1	INDUCTORS
		Coil.
TRANSISTORS		
Q201	19A134340P1	Silicon, NPN: VHF Amplifier, 4 watts, 12.5 v.
Q202A	19A134340P3	Silicon, NPN: VHF Amplifier, 12 watts.
Q202B	19A134340P2	Silicon, NPN: NHF Amplifier, 25 watts, 12.5 v.
Q203A	19A134340P4	Silicon, NPN, VHF Amplifier: 45 w.
Q203B	19A134387P1	Silicon, NPN.
Q204 and Q205	19A134387P1	Silicon, NPN.
Q215	19A116742P1	Silicon, NPN.
THERMISTORS		
RT201	19A129379G1	Thermistor: 40K ohms ±20%, color code white; sim to Carborundum Type M0806J-5.
CABLES		
W203	19A136942P1	Strap.
W204	7878455P1	Lug terminal; sim to GE89473.
W205	19B227912P1	Jumper.
W206	19B227931G3	Jumper.
W207	19B227931G1	Jumper.
W208	19B227074G1	Jumper. 6 inches long.
W209	19B226725G1	Jumper. 5-3/4 inches long.
W210	19B227934G1	Cable: approx 13 inches long.
W211	19A137006P2	Jumper.
CAPACITORS		
C297 and C298	19A116708P1	Ceramic: 0.01 uF -0 +100%, 500 VDCW, rated 20 amps; sim to Erie 327050X5W0103P.
C299	19A115680P10	Electrolytic: 200 uF +150-10%, 18 VDCW; sim to Mallory Type TTX.
DIODES AND RECTIFIERS		
CR295	19A116783P1	Rectifier, silicon: 100 VDC blocking, 6 amp; sim to MR751.
MISCELLANEOUS		
19D416732G7 and 19D417105G7		Heat sink. ("M" SERIES).
		Heat sink. ("E" SERIES).
	19A700068P1	Insulator, bushing. (Used with Q215).
19A700115P3		Insulator, plate. (Used with Q215).
	19C321982P1	Insulator. (Located under A201, A202).
	19C321442P1	Insulator. (Located under A203-A206).
NP280427		Nameplate. (25, 40, 65 Watt - Located on FL201).
	NP280428	Nameplate. (110 Watt - Located on FL201).
	19B201074P306	Tap screw, Phillips POZIDRIVE®: No. 6-32 x 3/8. (Located between FL201 cover and A203-A206 - Quantity 2).
N404P13C6		Lockwasher, internal tooth: No. 6. (Located between FL201 cover and A203-A206).
	19B201074P312	Tap screw, Phillips POZIDRIVE®: No. 6-32 x 3/4. (Secures FL201 cover).
	N44P9010C6	Machine screw: No. 4-40 x 5/8. (Secures Q1 & Q2 on A201, A202; Q1 on A204, A2095, Q1-Q3 on A206).

SYMBOL	GE PART NO.	DESCRIPTION
N80P13006C6		Machine screw, phillips head: No. 6-32 x 3/8. (Secures A201-A206 boards).
	N80P9006C6	Machine screw: No. 4-40 x 3/8. (Used with Q215 mounting).
	N402P5C6	Flatwasher, steel: No. 4. (Used with Q215 mounting).
7141225P2		Hex nut: No. 4-40. (Used with Q215 mounting).
19A129434P1		Washer, fiber. (Used with C297 & C298).
19B219929P1		Support, heat sink.
19B209209P306		Tap screw, Phillips POZIDRIVE®: No. 6-32 x 3/8. (Secures support to heat sink - Quantity 3).
19A129639P1		Cover, heat sink.
19B201074P305		Tap screw, Phillips POZIDRIVE®: No. 6-32 x 5/16. (Secures heat sink cover).
19D416275P2		Filter casting. (FL201).

PARTS LIST		
138-174 MHz POWER AMPLIFIER ASSEMBLIES		
19D424786G2-9		
ISSUE 9		
SYMBOL	GE PART NO.	DESCRIPTION
A201	19D424309G1	10 Watt Driver. (Used with 19D424786G2, G4, G5, G7).
A202	19D424309G3	25 Watt Driver. (Used with 19D424786G3, G6).
A204	19D424872G1	40 Watt Power Amplifier. (Used with 19D424786G2, G5).
A205	19D424872G2	65 Watt Power Amplifier. (Used with 19D424786G3, G6).
A206	19D424266G1	110 Watt Power Amplifier. (Used with 19D424786G4, G7).
A207	19D424266G2	130 Watt Power Amplifier. (Used with 19D424786G8, G9).
CAPACITORS		
C297 and C298	19A116708P1	Ceramic: 0.01 uF -0 +100%, 500 VDCW, rated 20 amps; sim to Erie 327050X5W0103P.
FILTERS		
COMPONENT BOARD 19C327454G1		
CAPACITORS		
C1	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
C2	19A700015P12	19A700015P12 Teflon/Mica: 22 pF ±5%, 250 VDCW.
C3	19A116795P29J	19A116795P29J Teflon: 29 pF ±5%, 250 VDCW.
C4	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
C5 and C6	19A116655P18	19A116655P18 Ceramic disc: 680 pF ±10%, 1000 VDCW; sim to RMC Type JF Discap.
JACKS AND RECEPTACLES		
J202 and J203	19A700049P2	19A700049P2 Connector, receptacle: 500 VDCW maximum; sim to NTPF-1058.
J206 and J207	19A134263P2	19A134263P2 Contact, electrical: sim to Selectro 229-1071.
J208	4033513P4	4033513P4 Contact, electrical: sim to Bead Chain L93-3.
RELAYS		
K1	19A700061P1	19A700061P1 Hermetic sealed: 180 to 341 ohms coil res, 8-16.3 VDC; sim to GE 3SAV1760A2, CPClare HPW-1201558, or Potter-Brumfield HCM6160.
INDUCTORS		
L1	19A129569P1	19A129569P1 Coil.
L2	19A701418P1	19A701418P1 Coil.
L3	19A129569P1	19A129569P1 Coil.
L4	19A701420P5	19A701420P5 Coil.
L5	19A129569P1	19A129569P1 Coil.
L6	19A701418P1	19A701418P1 Coil.

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
L6	19A701418P1	Coil.
L7	19A136907P1	Coil.
CABLES		
W1 thru W5		(Part of printed board 19D424357P1).
COMPONENT BOARD 19C327354G1 (Deleted by REV. B)		
CAPACITORS		
C1	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
C2	19A700015P12	19A700015P12 Teflon/Mica: 22 pF ±5%, 250 VDCW.
C3	19A116795P29J	19A116795P29J Teflon: 29 pF ±5%, 250 VDCW.
C4	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
JACKS AND RECEPTACLES		
J203	19A700049P2	19A700049P2 Connector, receptacle: 500 VDCW maximum; sim to NTPF-1058.
INDUCTORS		
L1	19A129569P1	19A129569P1 Coil.
L2	19A701418P1	19A701418P1 Coil.
L3	19A129569P1	19A129569P1 Coil.
L4	19A701420P5	19A701420P5 Coil.
L5	19A129569P1	19A129569P1 Coil.
L6	19A701418P1	19A701418P1 Coil.
CABLES		
W1 and W2		(Part of printed board 19D424362P1).
ANTENNA FILTER W MATCHER 19C327354G2 (Added by REV. B)		
ANTENNA FILTER 19D432249G1		
CAPACITORS		
C1	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
C2	19A700015P12	19A700015P12 Teflon/Mica: 22 pF ±5%, 250 VDCW.
C3	19A116795P29J	19A116795P29J Teflon: 29 pF ±5%, 250 VDCW.
C4	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
JACKS AND RECEPTACLES		
J1 thru J4	19A116364P2	19A116364P2 Contact, electrical; sim to AMP 86182-7.
J203	19A700049P2	19A700049P2 Connector, receptacle: 500 VDCW maximum; sim to NTPF-1058.
INDUCTORS		
L1	19A129569P1	19A129569P1 Coil.
L2	19A701418P1	19A701418P1 Coil.
L3	19A129569P1	19A129569P1 Coil.
L4	19A701420P5	19A701420P5 Coil.
L5	19A129569P1	19A129569P1 Coil.
L6	19A701418P1	19A701418P1 Coil.
CABLES		
W1 thru W3		(Part of printed circuit board 19D432086P1).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
COMPONENT BOARD 19C327354G1		
CAPACITORS		
C1	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
C2	19A700015P12	19A700015P12 Teflon/Mica: 22 pF ±5%, 250 VDCW.
C3	19A116795P29J	19A116795P29J Teflon: 29 pF ±5%, 250 VDCW.
C4	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
JACKS AND RECEPTACLES		
J203	19A700049P2	19A700049P2 Connector, receptacle: 500 VDCW maximum; sim to NTPF-1058.
INDUCTORS		
L1	19A129569P1	19A129569P1 Coil.
L2	19A701418P1	19A701418P1 Coil.
L3	19A129569P1	19A129569P1 Coil.
L4	19A701420P5	19A701420P5 Coil.
L5	19A129569P1	19A129569P1 Coil.
L6	19A701418P1	19A701418P1 Coil.
CABLES		
W1 and W2		(Part of printed board 19D424362P1).
ANTENNA MATCHER 19C330778G1		
CAPACITORS		
C1A	19A116192P1	19A116192P1 Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 Special.
C2	19A700008P2	19A700008P2 Variable: 2.28 to 14.13 pF; sim to EF Johnson 187-0109-005.
C3A	19A116656P1530	19A116656P1530 Ceramic disc: 15 pF ±5%, 500 VDCW, temp coef 0 PPM.
C4A	19A700008P2	19A700008P2 Variable: 2.28 to 14.13 pF; sim to EF Johnson 187-0109-005.
C5A	19A116656P1030	19A116656P1030 Ceramic disc: 10 pF ±0.5 pF, 500 VDCW, temp coef 0 PPM.
CAPACITORS		
C1	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
C2	19A700015P12	19A700015P12 Teflon/Mica: 22 pF ±5%, 250 VDCW.
C3	19A116795P29J	19A116795P29J Teflon: 29 pF ±5%, 250 VDCW.
C4	19A116679P8D	19A116679P8D Metalized teflon: 8 pF ±0.5 pF, 250 VDCW.
JACKS AND RECEPTACLES		
J1 thru J4	19A116364P2	19A116364P2 Contact, electrical; sim to AMP 86182-7.
J203	19A700049P2	19A700049P2 Connector, receptacle: 500 VDCW maximum; sim to NTPF-1058.
INDUCTORS		
L1A	19A143343P1	19A143343P1 Coil.
RESISTORS		
R1	19A700106P31	19A700106P31 Composition: 47 ohms ±5%, 1/4 w.
JACKS AND RECEPTACLES		
J213		Consists of: Housing. Contact, electrical. Part of W214. Part of C298. Part of W243. Part of W244.
L1	19A129569P1	19A129569P1 Coil.
L2	19A701418P1	19A701418P1 Coil.
L3	19A129569P1	19A129569P1 Coil.
L4	19A701420P5	19A701420P5 Coil.
L5	19A129569P1	19A129569P1 Coil.
L6	19A701418P1	19A701418P1 Coil.
CABLES		
L201	19A129562P4	19A129562P4 Coil.
L202	19A129562P3	19A129562P3 Coil.

		- - - - - PLUGS - - - - -
P206	4036634P1	Contact, electrical; sim to AMP 42428-2.
		- - - - - TRANSISTORS - - - - -
Q201	19A13434CP1	Silicon, NPN: VHF Amplifier, 4 watts, 12.5 v.
Q202A	19A13434CP3	Silicon, NPN: VHF Amplifier, 12 watts.
Q202B	19A13434CP2	Silicon, NPN: NHF Amplifier, 25 watts, 12.5 v.
Q203A	19A13434CP4	Silicon, NPN, VHF Amplifier: 45 w.
Q203B	19A134387P1	Silicon, NPN.
Q204 and Q205	19A134387P1	Silicon, NPN.
Q215	19A116753P1	Silicon, NPN; sim to Type 2N5302.
	19A116742P1	Earlier than REV A: Silicon, NPN.
		- - - - - THERMISTORS - - - - -
RT201	19A129379G1	Thermistor: 40K ohms ±20%, color code white; sim to Carborundum Type M0806J-5.
		- - - - - CABLES - - - - -
W203	19A136942P1	Strap.
W204	7878455P1	Lug terminal; sim to GE89473.
W205	19B227912P1	Jumper.
W210	19B227934G1	Cable: approx 13 inches long.
W211	19A137006P2	Jumper.
W214	19A129312614	Antenna Cable.
W220	19B22793162	Jumper.
W221	19B22793194	Jumper.
W243		CABLE ASSEMBLY 19A12931266
		- - - - - JACKS AND RECEPTACLES - - - - -
J203		Connector. Includes: Receptacle, coaxial: sim to Amphenol 83-798. Cover.
		- - - - - PLUGS - - - - -
P203	5491689P108	Plug. (Includes 10 inches of RF cable).
W244	5491689P104	Cable, RF: approx 4 inches long. (Includes J244).
		- - - - - MISCELLANEOUS - - - - -
	19A134016P1	Insulator, bushing. (Used with Q215). (Not Used).
	19A116023F3	Insulator, plate. (Used with Q215). (Not Used).
	19C321982P1	Insulator. (Located under A201 & A202).
	19C321442P1	Insulator. (Located under A204-A206).
	19B219404G1	Shield electrical. (Located under FL201 casting).
	19D416275P2	Casting. (FL201).
	19D417513G1	PA Cover.
	19B226212G1	Heat sink. (The 3 center heat sinks on 75, 100, 110 WATT & the only 2 heat sinks on the 40, 65 WATT power amplifiers).
	19B226212G2	Heat sink. (Located on J243 end of the 75, 100, 110 WATT Power amplifiers - Quantity 1).
	19B226212G3	Heat sink. (Located on W241 end of the 75, 100, 110 WATT Power amplifiers - Quantity 1).
	7150186P127	Spacer. (Termination for L201 & W221).
	N529P18C6	Plug button. (Used when C298 is not used - Duplex).

PARTS LIST

A201
138-174 MHz, 10 WATT DRIVER
19D424309G1
ISSUE 9

SYMBOL	GE PART NO.	DESCRIPTION
----- CAPACITORS -----		
C1A	19A700105P8	Mica: 12 pF + or -5%, 500 VDCW.
C2	7489162P39	Silver mica: 330 pF + or -5%, 500 VDCW; sim to Sprague Type 118.
C3	19A700105P28	Mica: 56 pF + or -5%, 500 VDCW.
C4A and C5A	19A700015P23	Teflon/Mica: 56 pF + or -5%, 250 VDCW.
C6	19A700015P37	Teflon/Mica: 220 pF + or -5%, 250 VDCW.
C8	19A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.
C9	19A116655P8	Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim. to RMC Type JF Discap.
C10A	19A700105P30	Mica: 68 pF + or -5%, 500 VDCW.
C11A	7489162P101	Silver mica: 5 pF + or - 10%, 500 VDCW; sim. to Sprague Type 118.
C12	19A700015P30	Silver mica: 110 pF + or -5%, 250 VDCW.
C13A and C14A	19A700014P33	Metallized teflon: 150 pF + or - 5%, 250 VDCW.
C15	19A700015P37	Teflon/Mica: 220 pF + or -5%, 250 VDCW.
C16	19A134202P15	Tantalum: 6.8 uF + or -20%, 35 VDCW.
C17	19A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.
C18	19A116655P8	Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim. to RMC Type JF Discap.
C20A	19A700015P27	Silver mica: 82 pF + or -5%, 250 VDCW.
C21A	19A700015P16	Teflon/Mica: 30 pF + or -5%, 250 VDCW.
C22B	19A700015P25	Silver mica: 68 pF + or -5%, 250 VDCW.
C23 thru C25	19A116655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C26	19A134202P15	Tantalum: 6.8 uF + or -20%, 35 VDCW.
C27	19A116655P19	Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
C28	19A116655P8	Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim. to RMC Type JF Discap.
C29 and C30	19A116655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C31	19A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.
C32 thru C34	19A116655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C35	19A134202P6	Tantalum: 22 uF + or -20%, 15 VDCW.
C36	19A134202P15	Tantalum: 6.8 uF + or -20%, 35 VDCW.
C37 thru C40	19A116655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C42 and C43	19A116655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C44	19A703314P4	Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.
C45	19A701602P13	Ceramic: 470 pF + or - 20%, 1000 VDCW; sim to Type JF Discap.
C46	19A116655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C48 thru C50	19A116655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C52	19A700006P17	Mica: 22 pF + or -5%, 250 VDCW; sim to Underwood 3HS0020.

SYMBOL	GE PART NO.	DESCRIPTION
----- RECTIFIERS -----		
CR1	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.
----- TERMINALS -----		
E1	19A134263P1	Contact, electrical: sim to Selectro 229-1082-00-0-590.
G1	19A134263P1	Contact, electrical: sim to Selectro 229-1082-00-0-590.
----- JACKS -----		
J201	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF-1058.
J205	19B219374G1	Connector: 9 contacts.
----- INDUCTORS -----		
L1	19A700024P25	Coil, RF: 10.0 uH + or - 10%, 3.70 ohms DC res max.
L3A	19A136530P1	Coil.
L4	19A701091G1	Coil.
L5A	19A136532P2	Coil.
L6	19A701420P5	Coil.
L7	19A701091G1	Coil.
L8A	19A129561P1	Coil.
L9A	19A701420P3	Coil.
L10A	19A129561P1	Coil.
L11	19A701091G1	Coil.
L12	19A129569P1	Coil.
L13	19A701419P3	Coil.
L14 thru L16	19A700024P25	Coil, RF: 10.0 uH + or - 10%, 3.70 ohms DC res max.
----- TRANSISTORS -----		
Q1	19A700023P1	Silicon, NPN; sim to Type 2N3904.
----- RESISTORS -----		
R1	19A700106P67	Composition: 1.5K ohms + or - 5%, 1/4 w.
R2	3R152P241J	Composition: 240 ohms + or -5%, 1/4 w.
R3	19A700106P32	Composition: 51 ohms + or - 5%, 1/4 w.
R4	19A700113P15	Composition: 10 ohms + or - 5%, 1/2 w.
R5A	19A700113P32	Composition: 51 ohms + or - 5%, 1/2 w.
R6	19A700113P15	Composition: 10 ohms + or - 5%, 1/2 w.
R7	3R152P274J	Composition: 270K ohms + or -5%, 1/4 w.
R8A	19A116559P106	Variable cermet: 10K ohms + or - 20%, 1/2 w; sim to CTS Series 360.
R9	19C850605P2	Shunt resistor.
R10	19A700113P51	Composition: 330 ohms + or - 5%, 1/2 w.
R11	3R152P564J	Composition: 560K ohms + or -5%, 1/4 w.
R12	19A700106P75	Composition: 3.3K ohms + or - 5%, 1/4 w.
R13	H212CRP910C	Deposited carbon: 1 ohm + or -5%, 1/4 w.
R15	19C850605P2	Shunt resistor.
R16	19A700106P61	Composition: 820 ohms + or - 5%, 1/4 w.
R17	19A700106P49	Composition: 270 ohms + or -5%, 1/4 w.
----- TRANSFORMERS -----		
T1	19A129564G1	Transformer.
----- INTEGRATED CIRCUITS -----		
U1	19D429709G3	IC, Power Control.

SYMBOL	GE PART NO.	DESCRIPTION
----- CABLES -----		
W1 and W2		(Part of printed board 19D424308).
W3	19B227912P1	Jumper.
W4	19B227912P2	Jumper.
----- MISCELLANEOUS -----		
	19A701093P2	Strap. (Solders to W2).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

PARTS LIST

A204
138-174 MHz 40 WATT POWER AMPLIFIER
19D424872G1
ISSUE 3

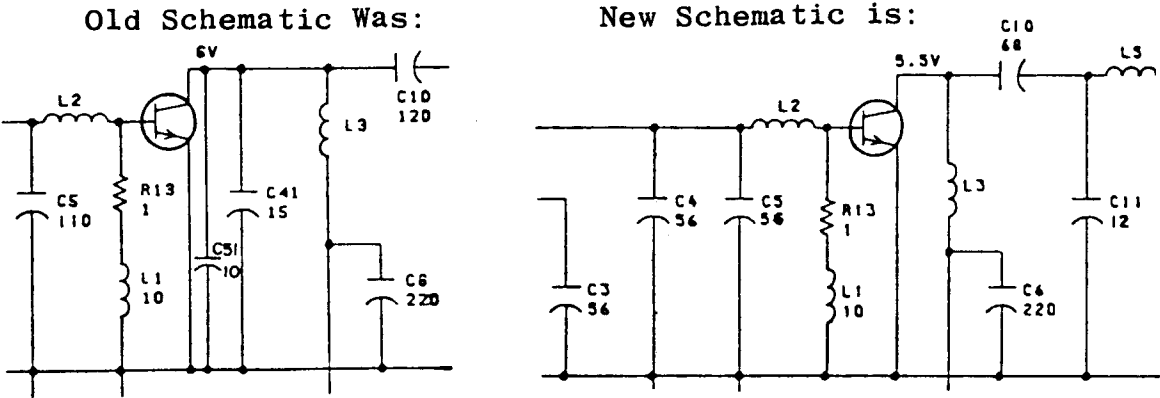
SYMBOL	GE PART NO.	DESCRIPTION
----- CAPACITORS -----		
C1A	19A700015P18	Metallized teflon: 36 pF $\pm 5\%$, 250 VDCW.
C2A	19A116795P160J	Silver mica: 160 pF $\pm 5\%$, 250 VDCW.
C3A and C4A	19A700014P38	Metallized teflon: 240 pF $\pm 5\%$, 250 VDCW.
C7A	19A700014P33	Metallized teflon: 150 pF $\pm 5\%$, 250 VDCW.
C8	19A700015P37	Teflon/Mica: 220 pF $\pm 5\%$, 250 VDCW.
C9A	19A700015P16	Teflon/Mica: 30 pF $\pm 5\%$, 250 VDCW.
C10A	19A700015P37	Teflon/Mica: 220 pF $\pm 5\%$, 250 VDCW.
C11	19A116655P13	Ceramic disc: 470 pF $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C12	19A134202P15	Tantalum: 6.8 uF $\pm 20\%$, 35 VDCW.
C13	19A116080P107	Polyester: 0.1 uF $\pm 10\%$, 50 VDCW.
C14A	19A700105P23	Mica: 39 pF $\pm 5\%$, 500 VDCW.
C15 thru C17	19A116655P13	Ceramic disc: 470 pF $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C19 thru C21	19A116655P13	Ceramic disc: 470 pF $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C22	19A134202P15	Tantalum: 6.8 uF $\pm 20\%$, 35 VDCW.
C23 thru C30	19A116655P13	Ceramic disc: 470 pF $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C31	19A134202P15	Tantalum: 6.8 uF $\pm 20\%$, 35 VDCW.
C32 and C33	19A116080P107	Polyester: 0.1 uF $\pm 10\%$, 50 VDCW.
----- DIODES AND RECTIFIERS -----		
CR1 and CR2	19A116052P2	Silicon, fast recovery; sim to Hewlett Packard 5082-2811.
----- INDUCTORS -----		
L1A	19A136533P1	Coil.
L2		(Part of printed board 19D424845P1).
L3	19A701091G1	Coil.
L4A	19A701848P1	Coil.
L5A	19A137271P1	Coil.
L6A	19A129561P1	Coil.
L7 thru L9	19A700024P13	Coil, RF: 1.0 uH $\pm 10\%$.
----- RESISTORS -----		
R1A	7147161P17	Composition: 1.5 ohms $\pm 5\%$, 1/2 w.
R2 and R3	19A700109P1	Variable, cermet: 1K ohms $\pm 20\%$, 1/4 w.
R4	19A700106P32	Composition: 51 ohms $\pm 5\%$, 1/4 w.
R5A	19A700106P33	Composition: 56 ohms $\pm 5\%$, 1/4 w.
----- CABLES -----		
W1 thru W4		(Part of printed board 19D424845P1).
W30 and W31	19A701093P2	Strap.

SYMBOL	GE PART NO.	DESCRIPTION
----- NETWORKS -----		
Z1	19B219649G1	Filter. Includes:
L1	19A129346G2	Coil.
R1	3R78P100K	Resistor, composition: 10 ohms $\pm 10\%$, 1 w.
----- MISCELLANEOUS -----		
	19A139361P2	Shield.

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for the descriptions of parts affected by these revisions.

- REV. A - 10 WATT DRIVER 19D424309G1
To improve operation when Solid State Scientific, Inc. (SSS) transistors are used for Q201. Delete C39. Change C11 and add L2.
- REV. B - To improve operation when Communication Transistor Corp. (CTC) transistors are used for Q201. Delete C39, add L2. Changed C11 and added C51.
- REV. C - To improve operation when TRW transistors are used for Q201. Deleted C51 and L2. Added C39 and changed C11.



- REV. D - To improve performance. Changed R5.
- REV. E - To improve operation of power control circuit. Added C51.
- REV. F - To delete components not required with improved Power Control IC. Deleted C51.
- REV. A - 40 WATT POWER AMPLIFIER 19D424872
To improve operation. Changed R1.
- REV. B - PA ASSEMBLY 19D424786G5
To incorporate new antenna matching unit PL202. PL202 was: 19C327354G1.
- REV. H - 10 WATT DRIVER 19D424309G1
To reduce transmitter spurs. Added C52.
- REV. J - 10 WATT POWER AMPLIFIER 19D424309G1
To improve operation of power amplifier by modifying power control circuit to eliminate overshoot at key-on. Added Q1, C44, C45, R16, and R17.

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES